

SEMICONDUCTOR TECHNICAL DATA

MPSA06

EPITAXIAL PLANAR NPN TRANSISTOR

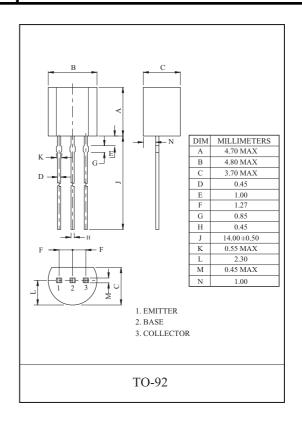
DRIVER STAGE AMPLIFIER APPLICATIONS. VOLTAGE AMPLIFIER APPLICATIONS.

FEATURES

· Complementary to MPSA56.

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current	I_{C}	500	mA
Emitter Current	I_{E}	-500	mA
Collector Power Dissipation	$P_{\rm C}$	625	mW
Junction Temperature	T _j	150	$^{\circ}$
Storage Temperature	T_{stg}	- 55 ∼150	$^{\circ}$



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 80V, I_{E} = 0$	-	-	100	nA
Emitter Cut-off Current	I _{CEO}	$V_{CE}=60V, I_{B}=0$	-	-	100	nA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	$I_C=1 \text{ mA}, I_B=0$	80	-	-	V
DC Current Gain	h _{FE} (1)	V _{CE} =1V, I _C =10mA	100	-	-	
	h _{FE} (2)	V _{CE} =1V, I _C =100mA	100	-	-	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =100mA, I _B =10mA	-	-	0.25	V
Base-Emitter Voltage	V_{BE}	V _{CE} =1V, I _C =100mA	-	-	1.2	V
Transition Frequency	f_T	$V_{CE}=2V$, $I_{C}=10mA$	100	-	-	MHz

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